Self-Regenerating Soft Biophotovoltaic Devices

Xinkai Qiu, †‡,§ Olga Castañeda Ocampo, †‡,§ Hendrik W. de Vries, † Maikel van Putten, † Mark Loznik, † Andreas Hermanni, †∥⊥ and Ryan C. Chiechi*†‡

†Zernike Institute for Advanced Materials, Nijenborgh 4, 9747 AG Groningen, The Netherlands
‡Stratingh Institute for Chemistry, University of Groningen, Nijenborgh 4, 9747 AG Groningen, The Netherlands
§Supporting Information

ABSTRACT: This paper describes the fabrication of soft, stretchable biophotovoltaic devices that generate photocurrent from photosystem I (PSI) complexes that are self-assembled onto Au electrodes with a preferred orientation. Charge is collected by the direct injection of electrons into the Au electrode and the transport of holes through a redox couple to liquid eutectic gallium-indium (EGaIn) electrodes that are confined to microfluidic pseudochannels by arrays of posts. The pseudochannels are defined in a single fabrication step that leverages the non-Newtonian rheology of EGaIn. This strategy is extended to the fabrication of reticulated electrodes that are inherently stretchable. A simple shadow evaporation technique is used to increase the surface area of the Au electrodes by a factor of approximately 10^6 compared to planar electrodes. The power conversion efficiency of the biophotovoltaic devices decreases over time, presumably as the PSI complexes denature and/or detach from the Au electrodes. However, by circulating a solution of active PSI complexes the devices self-regenerate by mass action/self-assembly. These devices leverage simple fabrication techniques to produce complex function and prove that photovoltaic devices comprising PSI can retain the ability to regenerate, one of the most important functions of photosynthetic organisms.

KEYWORDS: photosystem I, self-assembly, EGaIn, microfluidics, cofabrication, stretchable photovoltaics

INTRODUCTION

Emerging challenges in the fabrication of microelectronic devices are driving research into simple, rapid, and inexpensive fabrication strategies that are amenable for a large variety of materials and architectures.1,2 Cofabrication is such a strategy3 which simplifies the fabrication of multicomponent microelectronic devices compared to, for example, multilayer microfabrication, a commonly-used technique for fabricating field-effect transistors, photovoltaic devices, etc. It uses microfluidic channels, fabricated by using soft lithography, to provide the single structural basis (the master) for all the components and their functions that are required in the final device, which is produced by sealing the channels against a flat substrate and filling them with different materials to generate desired functions. Cofabrication is capable of generating microcomponents that are correctly aligned, in a single lithographic step, over a large surface area, avoiding registration and improving the efficiency of fabrication. It is also useful as a laboratory-scale rapid-prototyping technique because devices can be manufactured from inexpensive materials (e.g., poly(dimethylsiloxane) (PDMS),4 thiolene resins,5 polycarbonate,6 glass,7,8 etc.) and simple methods (e.g., soft lithography, heat embossing, etc.) while consuming less solvent and photoresist compared to conventional fabrication strategies.

Cofabricated microfluidic systems based on silicone elastomers such as PDMS and Ecoflex9 have shown potential as wearable electronic devices, including health monitors.10,11 However, the incorporation of conductive microcomponents with correct alignment and stable electronic properties remains a challenge. The common approach to fabricate conductive microcomponents on flat substrates involves the patterning (e.g., shadow mask and lithography) and deposition (e.g., thermal evaporation, electron beam evaporation, and sputtering) of metals.12–14 As the size and complexity of the pattern grows, aligning the microcomponents with microfluidic channels without cracking the pattern during fabrication becomes more difficult. Alternative approaches focus on installing thin metallic films onto the side walls of the microfluidic channels by deposition at an angle15 and ion milling to etch thin films into desired shapes,16 which adds complexity to the fabrication. Organic materials mitigate some of this complexity, but their relatively low electrical mobility and oxidative instability remain problematic.17 Eutectic gallium–indium (EGaIn 75%, Ga 25%) In by weight, melting point 15.5 °C) combines the advantageous properties of...
metallic films and organic materials. It rapidly forms flexible electronic components in pre-patterned microfluidic channels by injection at room temperature, an example of cofabrication that obviates the need for registration and multistep fabrication. EGaIn has also been used to fabricate stretchable interconnects and antennas in microfluidic systems.

A comparable approach to simplifying the fabrication of devices with complex functionality is to co-opt naturally occurring structures such as photosystem I (PSI) to fabricate photovoltaic devices. Combined with self-assembly, complex nanostructures can be fabricated simply, en masse. While the efficiencies of such biophotovoltaic (bio-PV) devices remain far from commercial viability, cofabrication makes it possible to explore self-repair and self-regeneration, which are vital to living systems, but do not readily translate to thin-film devices. Cofabricated microfluidic channels enable the incorporation of materials in different forms that can be removed or replaced in the same device to produce microheaters, in-plane electromagnets, optofluidic waveguides, switches and couplers, lenses, light sources, microdroplet generators, and chemical reactors. Combining these traits with the self-assembly of PSI on metallic electrodes potentially allows the replacement of inactive PSI, in operando.

In this paper, we introduce a simple strategy to construct a stretchable network of EGaIn microelectrodes in a cofabricated microfluidic chip to form bio-PV devices that operate similarly to dye-sensitized solar cells. Due to the unique rheology of EGaIn, regularly-spaced PDMS posts confine the EGaIn microelectrodes to pseudochannels that are spatially separated from other fluid-filled microfluidic channels, but are still in chemical contact. This design (electro)chemically couples EGaIn to Au electrodes functionalized with PSI via an electrolytic medium. By reducing the surface free-energy of EGaIn during the injection, we significantly increased the length of the EGaIn microelectrodes, enabling the formation of reticulated electrodes/channels to increase the volume fraction of the PDMS chip taken up by the electrodes. The reticulated EGaIn electrodes are inherently stretchable and can be deformed without losing their structure or electrical conductivity. We fabricated bio-PV devices by immobilizing trimers of PSI via self-assembly with selective orientation onto nanostructured Au electrodes in microfluidic channels flanked by EGaIn microelectrodes. Circulating PSI through the resulting solar cells caused the devices to self-regenerate via the spontaneous replacement of inactive PSI by active PSI from solution.

RESULTS AND DISCUSSION

**Biophotovoltaic Device Design.** A typical device begins with a straight 475 μm-wide channel formed in PDMS and partitioned by a row of 50 μm-diameter posts separated by 50 μm as shown in Figure 1A. A strip of smooth, template-stripped Au (AuTS) is placed on a flat PDMS substrate and modified with a self-assembled monolayer (SAM) of a short linker molecule (sodium 3-mercaptop-1-propanesulfonate, MPS). As depicted in Figure 1B, when exposed to a solution of PSI, this “director” SAM biases the PSI to self-assemble (Figure S7) such that the electron transport chain will inject electrons into the AuTS electrode when illuminated. After functionalizing the AuTS electrode with PSI, the channel is sealed against it such that half of the channel overlaps with the electrode. To form the counter electrode, EGaIn is injected into the side of the channel that is not occupied by the AuTS/PSI electrode. The array of the posts both guides the flow of EGaIn into this pseudochannel and keeps it confined on one side of the posts such that it occupies the same channel as the AuTS electrode, but does not touch it, as is shown in Figure 1C. Because the AuTS electrodes are aligned with the PDMS posts by hand, the distance between the AuTS electrode and the posts ranges from 10 to 80 μm. To complete a bio-PV device, a redox couple consisting of an aqueous solution of ascorbic acid (5 mmol) and 2,6-dichlorophenolindophenol (DCPIP, 0.1 mmol) is injected into the microfluidic channel that is defined by the EGaIn electrode such that the EGaIn and AuTS are both in contact with the solution, but do not touch each other.

Figure 1 shows a completed device. We chose a redox couple that is widely used to study the activity of PSI by oxygen consumption measurement, but not necessarily optimized for photovoltaics. It operates in three steps: (i) PSI absorbs a photon and injects an electron into the AuTS electrode; (ii) DCPIP transfers an electron to PSI, regenerating its ground state; and (iii) ascorbic acid transfers an electron to DCPIP and then diffuses to the EGaIn electrode where it is reduced by EGaIn to complete the redox cycle (Figures 1B and S13).
As expected, illuminating the cofabricated PDMS chips containing EGaIn/AuTS/PSI leads to a measurable short-circuit current density JSC. To ensure that PSI is responsible for JSC we measured control devices that lack PSI or that are fabricated using boiled (denatured) PSI. These results are summarized in Figure S2 and Table S2; while devices lacking active PSI result in a small JSC it increases dramatically for devices containing active PSI. The non-zero JSC from the control devices are likely due to (inefficient) charge-transfer between the redox couple and the Au electrode under illumination either from the excitation of DCPIP or plasmon resonances in Au.

**Electrode Surface Area.** While the bio-PV device described above is functional and simple to fabricate, there are three parameters that can be optimized to increase the power conversion efficiency η: (i) the redox couple, (ii) the volume fraction of the PDMS chip occupied by the active PV components, and (iii) the surface area of the Au electrode. We focused only on the latter two because they impact the complexity of the device.

To maximize the surface area of the Au electrode, we used a shadow evaporation technique that we developed previously.51 Briefly, Au is vapor-deposited at an angle onto a rotating array of porous alumina (an anodic aluminum oxide (AAO) membrane filter, Figure S8) that is later dissolved to leave behind an Au substrate decorated with densely-packed, hollow nanotubes of Au standing perpendicular to the surface (Figure S9). The thickness of the walls, diameter, and height of the tubes can be controlled by the angle, deposition time, and pore diameter, which we optimized to accommodate PSI. The surface area of the shadow-evaporated Au (AuSE) electrodes increases by a factor of ∼10^6 compared to AuTS (see the Supporting Information). To test the hypothesis that this increase in the surface area results in higher JSC, as calculated from the macroscopic area of the electrodes, we performed systematic measurements on the performance of the bio-PV devices fabricated using both. Figure 2 compares the performance of two sets of devices fabricated from template AuTS and AuSE under four cycles of light (1 min) and dark (4 min) over a period of 20 min. For devices fabricated using AuSE, JSC (μA/cm^2) = 64, 64, and 47. For devices fabricated using AuTS, JSC (μA/cm^2) = 2, 4, and 1 (see Table S1). The average JSC of the devices fabricated using AuSE was a factor of 75 larger than that of those fabricated using AuTS, reflecting the increased density of PSI on AuSE electrodes. We observed a maximum decrease of 16% in JSC after the first two light/dark cycles in the devices fabricated using AuSE, but it remained stable in the later cycles over more than 10 min under ambient conditions or under continuous illumination (Figure S3). Comparing the stability of PSI-based bio-PV devices to literature reports is difficult because other devices are typically only tested for about 30 s29,52,53 and use redox couples dissolved in organic solvents29 that quickly denature the PSI. Our devices are intrinsically more stable (which we discuss in more detail below) because they use aqueous electrolytes.

We further investigated the J/V characteristics of bio-PV devices fabricated using AuSE to measure the power conversion efficiency η and the open-circuit voltage VOC. Figure 3A shows the J/V curve of a typical device measured in the dark and under irradiation with 655 nm light; VOC = 0.5 V and JSC = 180 μA/cm^2. Figure 3B shows the power output as a function of potential from which we calculate a maximum power output of 13.5 μW/cm^2 and a fill factor (FF) of 0.15 to give η = 0.0025%. While this η is clearly not technologically useful, it is reasonably compared to other bio-PV devices based on PSI 29,52 and, as mentioned above, our devices are intrinsically more stable, which leaves room for further optimization. For example, using phage display to increase the fraction of PSI with the correct orientation 24 to inject an electron into the AuSE electrode and substituting Au with other materials to better match the work function to the excited state of PSI (the
shadow evaporation technique is not limited to Au, in addition to optimizing the redox couple. However, the purpose of this work is to demonstrate the use of cofabrication to make soft, self-regenerating devices—to focus on the unique properties of PSI rather than maximizing $\eta$, which remains as a future challenge. We also characterized the device under AM1.5 solar illumination, however, the photoresponse from the device was too weak to distinguish from the noise level. This is possibly due to the low absorption of the monolayer of PSI to incident light and significantly smaller power flux of solar illumination compared to laser light.

Reticulated Cofabricated Electrodes. Due to the design of our devices, that places the EGaIn electrode perpendicular to the AuSE electrode, the PSI complexes are illuminated through PDMS rather than, for example, a transparent electrode material and the devices can be stacked since the electrodes are completely encapsulated. This design has the advantage that PDMS is completely transparent at the wavelengths of light absorbed by PSI and the disadvantage that the volume fraction of a square chip occupied by straight channels is low enough that most of the light will pass through without interacting with PSI. Reticulated channels significantly increase the fraction of the chip occupied by AuSE, but thus far only straight cofabricated channels have been demonstrated.

To investigate whether cofabricated channels can turn corners and still confine EGaIn behind an array of posts, we fabricated four types of EGaIn microelectrodes by injecting the liquid metal into PDMS microchannels: (A) two straight electrodes flanking a fluidic channel; (B) L-shape electrode; (C) three reticulated electrodes; and (D) a reticulated electrode flanked by two fluidic channels (Figure 4). EGaIn electrode A has been previously reported, but is limited to straight channels.48 We extended this fabrication technique to produce the latter three types of electrodes, which increase the volume fraction (and surface area) of EGaIn that can be incorporated in a single step. The PDMS posts not only separate channels, but also guide the flow of EGaIn during injection. We reproduced electrode (A) as reported48 where the width of the channel was 375 $\mu$m and distance between two neighboring posts was 50 $\mu$m. EGaIn will fill the electrode pseudochannels without leaking through the posts as long as the critical pressure to drive EGaIn into the channels is smaller than through the posts. For the L-shape electrode (B), we kept the distance between posts at 50 $\mu$m and EGaIn still filled the electrode pseudochannels without leaking. Notably, the meniscus formed by EGaIn between PDMS posts in (B) has a smaller radius of curvature than (A), which can be explained by the increase in the critical pressure required to inject EGaIn.
through the electrode channel in (B) due to increased curvature of the channel; EGaIn was less resistive to flow through the posts. To fabricate EGaIn electrodes (C) and (D), water must first be injected into the channels to create a slip layer between EGaIn and PDMS that allows the liquid metal to flow smoothly instead of sticking to the surface of PDMS. However, the yields of (C) and (D) were significantly lower than their counterparts since we decreased the width of the channels to 160 μm while keeping the distance between the posts at 50 μm. The slip layer is necessary to prevent the leakage of EGaIn through the posts because it lowers the critical pressure to drive EGaIn through the channel more than through the posts. The meniscus of central EGaIn electrode in (C) shows a larger radius of curvature than its counterparts in the side channels, indicating that a lower pressure is required to inject EGaIn into a channel with posts on both sides than on single side. Thus, one EGaIn pseudochannel can create an electrode that is coupled to two PSI/Au electrodes in a single step.

To study the mechanical and electrical stability of the EGaIn electrodes, we measured the conductance $G_{\text{meas}}$ of an EGaIn electrode versus the strain applied to the PDMS chip. We applied a maximum strain of 70% to measure in the elastic region of the PDMS chip (Figure S1) and a fixed bias of 0.1 V at the inlet of the microelectrode and grounded the outlet. We measured three types of EGaIn electrodes: (A) an EGaIn electrode defined in a pseudochannel separated by a single row of pillars of PDMS (Figure 5A, left); (B) an EGaIn electrode defined in a pseudochannel separated by rows of pillars of PDMS on either side of the electrode (Figure 5A, center); and (C) a reticulated EGaIn electrode defined in a serpentine pseudochannel separated by rows of pillars of PDMS on either side of the electrode (Figure 5A, right). Figure 5B shows that the three different types of electrodes return to their initial configuration after stretching (i.e., they do not leak).

We modeled the change in conductance $G_{\text{calc}}$ of the EGaIn anticipated due to the deformation of the electrode during stretching by treating it as a cuboid and calculating the conductance as a function of strain

$$G_{\text{calc}} = \frac{1}{R} = \frac{A}{\rho L} = \frac{V}{\rho L^2} = \frac{V}{\rho L_0^2 (\epsilon + 1)^2}$$

where, $R$ is the resistance, $\rho$ is the resistivity, $L$ is the length of the cuboid, $A$ is the cross-section of the cuboid, $V$ is the volume of the cuboid, $L_0$ is the original length of the cuboid, and $\epsilon$ is the strain of the cuboid. As long as $G_{\text{meas}} \geq G_{\text{calc}}$, the EGaIn electrodes are intact and are deforming with the PDMS chip without rupturing.

Figure 6 shows that the $G_{\text{meas}}$ is stable at low strain and drops sharply, approaching $G_{\text{calc}}$ around 25% strain and leveling off again around 60% strain (see also Figure S12). Equation 1 suggests that in an ideal case, $G$ is proportional to $1/(\epsilon + 1)^2$, which disagrees with the experimental data as shown in Figure 6A. When the device is stretched, the cross-sectional area of the microchannel is reduced, leading to an increasing shear stress (defined by the ratio between the force and the cross-section area parallel to the force vector) on the EGaIn electrode. Because of the unique shear-thinning properties of EGaIn, the electrode is resistive to deformation at a low shear stress, thus, the small change of conductance before the strain is at 25%. As the shear stress continues to build, EGaIn yields and flows to the inlet and outlet of the microchannel, decreasing the cross-section area of the electrode. The plateau around 60% is likely due to non-uniform stretching of the PDMS (e.g., necking). Importantly, $G_{\text{meas}} \geq G_{\text{calc}}$ for all values of strain and $G_{\text{meas}}$ returns to its initial value when the strain is removed (Figure S10).

To further test the stretchability of working devices, we measured the evolution of photocurrent densities of devices fabricated from AuSE electrodes under 10 stretch/release cycles. We applied a strain of 18% on the devices during each cycle and recorded their photoreponse after the cycle (Figure 6B). The tested devices produced stable photocurrents that fluctuate randomly instead of showing a clear trend of decay, which suggests that the integrity of the devices was preserved and the device is stretchable under a certain level of strain.

**Regeneration.** The reversible interaction between the charged surface residues of the PSI sub-units and the sulfonate moiety of the MPS linker not only facilitates the immobilization and orientation of the complexes, but also enables the exchange between the immobilized and the free PSIs (i.e., by mass action/self-assembly). Thus, exposure to a solution of active PSI should result in the recovery of $J_{\text{SC}}$ of an aged device as inactive PSI is displaced from the surface of the AuSE electrode and replaced with active PSI from solution. To test this hypothesis, we measured $J_{\text{SC}}$ for three different bio-PV devices over 12 days. On day six, we circulated a solution of active PSI through the pseudochannel containing the redox couple and PSI/AuSE. Figure 7 shows that $J_{\text{SC}}$ decreased in time for all three devices over the first three days, recovered to

![Figure 6](image-url)

Figure 6. A) Plots of the experimental conductance $G_{\text{meas}}$ (red) and calculated conductance $G_{\text{calc}}$ (black) from eq 1 of EGaIn electrodes as a function of applied strain. (B) Evolution of the average photocurrent density of two devices fabricated from AuSE under 10 stretch/release cycles. The dashed line indicates the average photocurrent density before and after the cycles.
values greater than or equal to the initial values and then continued to decrease over the subsequent three days. It is not clear why $J_{SC}$ increased above the initial values, but in no case did they exceed the maximum observed value for the as-fabricated devices shown in Figure 2. To exclude the effect that the electrolyte was also replenished in the regeneration of PSI, we performed a control experiment in which only the electrolyte was also replenished in the regeneration of PSI, fabricated devices shown in Figure 2. To exclude the e

To gain more insight into the effectiveness of the self-regeneration, we investigated the evolution of $V_{OC}$, $J_{SC}$, and FF before and after the infusion of active PSI (Figure S4 and Table S3). The $V_{OC}$ does not show a significant decay during the measurement, however, the FF of the device decreases by 22% over six days before or after the exchange, which suggests that back electron transfer and recombination increase as the device degrades. Commensurate with $J_{SC}$, the FF increased above the value at Day One after the infusion.

There are two plausible, simultaneous mechanisms for the degradation in the performance of the bio-PV devices over time; denaturation of the PSI units and dissociation of the PSI complexes from the surface. The drop in $J_{SC}$ can be ascribed to either: it is a reflection of the decrease in the absolute number of active PSI complexes. The drop in the FF could be the result of partially denatured PSI sub-units with intact antenna complexes that can still absorb light, but cannot inject an electron into the AuSE electrode. The fact that the $V_{OC}$ does not decrease is a strong indication that $J_{SC}$ is always generated by PSI, a value that is determined by the electron transport chain in the reaction center of PSI and the redox potentials of the redox couples. When a typical PV device (e.g., Si p/n or organic/hybrid bulk-heterojunction) degrades, traps form, causing a drop in the $V_{OC}$ because the energy levels are defined by a band structure. The stability of the $V_{OC}$ is a reflection of the fact that, in effect, each PSI complex functions as a separate photovoltaic generator.

### Conclusions

The leaves of plants are mechanically deformable structures that generate (chemical) energy from light and that self-regenerate via a circulatory system. Using a simple strategy of cofabrication and self-assembly, we have demonstrated soft, stretchable bio-PV that are capable of self-regeneration via an open circulatory system into which active PSI can be infused—apart from their appearance, these devices share key properties with leaves. The design of the reticulated electrode/pseudochannel structure allows devices to be stacked to compensate for the relatively low optical cross-section, not entirely unlike the hierarchal stacking of thylakoids and chloroplasts.

Although bio-PV devices based on PSI are a long way from technological relevance, the fundamental appeal of co-opting proteins from the photosynthetic pathways of living organisms is the potential to incorporate the remarkable properties of photosynthetic organisms into artificial devices. Further study is needed to optimize the power conversion efficiency and better understand the mechanism of degeneration and self-regeneration, but we have demonstrated that PSI is the active component of our bio-PV devices and, therefore, that the recovery of degraded devices is due to the spontaneous replacement of inactive PSI by active PSI from solution.

### Experimental Section

**Cell Growth.** The thermophilic cyanobacterium *Thermosynechococcus elongatus* BP-1 was grown under agitation (180 rpm) in BG11 medium with continuous CO$_2$ supply at 1 L/min. The temperature was kept at 55 °C, continuous light applied at 50–60 μEinstein m$^{-2}$ s$^{-1}$ and cell growth pursued until late log phase. At last, the cells were harvested by centrifugation (JLA 9.100 rotor, Beckman; 5000 g; 15 min) and resuspended in Buffer A (20 mM 4-(2-hydroxyethyl)-1-piperazineethanesulfonic acid of pH 7.5; 10 mM MgCl$_2$; 10 mM CaCl$_2$; 500 mM Mannitol).

**Thylakoid Membrane Preparation.** Thylakoid membranes were prepared according to the following protocol, which represents a combination of two previously described preparation methods. To this end, fresh or frozen cells were resuspended in Buffer A and homogenized five times using a Dounce homogenizer. After the addition of lysozyme and DNase I (final concentrations: 5 mg/mL and 10 μg/mL, respectively), the cell suspension was incubated under slow agitation for 1 h at 37 °C in the dark. Subsequently, the cells were lysed by three passages through a French Press (15,000 psi; Constant Systems Limited, U.K.). Membranes were collected by centrifugation (JLA 16.250 rotor, Beckman; 38,000g; 20 min) and washed with Buffer A containing 3 M NaBr. Afterwards, the membrane suspension was washed once with Buffer A and three times with a buffer containing 0.05% n-dodecyl-$β$-D-maltoside (DDM) to remove the phycobilisomes. Finally, the thylakoid membranes were solubilized by incubation in Buffer A and supplemented with 0.6% DDM for 30 min at 20 °C in the dark. Nonsolubilized material was pelleted by centrifugation (JLA 16.250 rotor, Beckman; 38,000g; 20 min) and the supernatant was subjected to subsequent purification steps.

**Photosystem I Purification.** For PSI purification, fast liquid protein chromatography was applied on solubilized thylakloid...
membranes. The chromatographic purification was performed on an AKTA explorer (GE Healthcare) using an anion exchange column (HiTrap Q HP, GE Healthcare). After column equilibration with Buffer A + 0.03% DDM, the sample was applied and subsequently eluted by a linear gradient of 0–1 M MgCl₂. The green fluorescent fractions were collected and desalted with Buffer A + 0.03% DDM using Vivaspin 20 columns (molecular weight cut-off: 100 kDa, GE Healthcare). Finally, the purified PSI sample was adjusted to a Chl a concentration of 300 μM (with Buffer A + 0.03% DDM), snap-frozen in liquid nitrogen and stored at −80 °C.

**Determination of Chl a and Protein Concentration.** Chl a determination was performed in 100% methanol as described by Porra et al.58

**Fabrication of Microfluidic Channels.** The fabrication of EGaIn microelectrodes begins with the generation of master patterns of microchannels on a silicon wafer using a negative photoresist (SU-8, Microchem). Curing PDMS over the patterns produces an inverse replica of the master and sealing it to a flat slab of PDMS defines the channels into which EGaIn is injected at a constant rate using a syringe pump. We designed the film mask (JD Photodata) for UV lithography on Clewin. We cleaned a 3 in. silicon wafer with acetone and isopropanol, and annealed it on a hotplate at 200 °C for 5 min. After cooling the wafer to room temperature, we spin-coated 3 mL SU-8 photoresist on it in two stages: stage (1) with a velocity of 500 rpm, acceleration of 100 rpm/s for 13 s; stage (2) with a velocity of 500 rpm, acceleration of 300 rpm/s for 45 s. We then soft-baked the sample on a programmable hotplate in two stages: stage (1) the temperature increased from room temperature to 95 °C in 35 min and maintained for 6 min; in stage (2) the sample is allowed to slowly cool down to room temperature. We transferred the sample to the UV Mask Aligner for exposure. The mask was aligned with the sample to assure all patterns were projected onto the sample. We then exposed the sample to UV light (dosage 185−250 mJ/cm²) for 34 s. Post exposure bake was again carried out on a programmable hotplate in two stages: stage (1) the temperature increased from room temperature to 95 °C in 75 min and maintained for 1 min; in stage (2) the sample was allowed to slowly cool down to room temperature in a period of 6 h. We developed the sample by immersing the sample into the developer (MR-Dev 600) on a glass Petri dish for 5 min and rinsed the sample with isopropanol. This procedure was cycled three times to assure the complete removal of the unexposed SU-8 photoresist and eventually the sample was dried in N₂ to yield the master. We mixed the base and the curing agent (Sylgard 184 Silicone Elastomer) in a 10:1 (v/v) ratio by stirring and degassed the mixture in a desiccator for 30 min. Then we carefully poured the mixture over the master in a plastic Petri dish and baked it at 60 °C for 2 h.

**Fabrication of Shadow-Evaporated Au Electrode.** We mounted the AAO membranes (Whatman Anodisc) against a rotating plate (3 rpm). We centered the plate directly over the source and mounted the AAO membranes against a rotating slab of PDMS deionized water and ethanol, and subsequently the electrode was dried in a continuous N₂ flow. We first applied the aqueous solution of sodium 3-mercaptop-1-propanesulfonate (1 mM, MPS, Sigma-Aldrich, used as received) to cover the whole electrode under the protection of a N₂ atmosphere, allowing the formation of MPS SAM on the surface of Au in 2 h. We then rinsed the sample with deionized water and immersed it in an aqueous solution of PSI (1.04 μM) under the protection of a N₂ atmosphere for 2 h to immobilize PSI onto the electrode. After rinsing the sample with deionized water and drying it under N₂ flow, we encapsulated the Au electrode in one of the two microfluidic channels by manual alignment under an optical microscope. Then, we filled the other channel with EGaIn at a rate of 0.5 mL/h to prevent any possible leakage between the PDMS posts due to high pressure while keeping the injection relatively fast. The channel of Au electrode was filled with an aqueous solution of ascorbic acid (5 mM) and dichlorophenolindophenol (DCPIP, 0.1 mM). Then, we sealed the inlet and outlet of the channel of the Au electrode with Kapton tape for measurement.

**Measurement of Photocurrent.** The device was allowed to cool down to 0 °C and remained at that temperature before the measurement. We connected the bottom Au electrode and the EGaIn electrode to a Keithley sourcemeter (model 6430 sub-femtoamp remote sourcemeter), which can be controlled from a graphical user interface. The laser (655 nm, 62 mW) was fixed 9 mm above the surface of the device. For the measurement of light/dark cycles, the laser was on for 1 min and off for 4 min over 4 cycles in 20 min. For the measurement of J−V characteristics, the device was measured in a bias window from −0.1 to 0.8 V (0 → 0.8 → −0.1 → 0 V) with a step size of 0.01 V.

**Measurement of the Mechanical Properties.** All devices were measured on Instron 5943 equipped with a 1 kN load cell. The devices were held by two hydraulic grips and stretched at a constant rate of 3 mm/min (strain rate 0.0016/s). The gauge length between the two grips was measured by the software Bluehill 3 to interpret the Young’s modulus of the devices. A bias of 0.1 V was applied between the outlet and inlet of the EGaIn microelectrodes through copper wires while the devices were being stretched. The currents were recorded by a Keithley 2400 instrument and recalculated into conductivity for better understanding. Three stretch/release cycle was performed on each EGaIn electrode with a strain magnitude of 70%.

### ASSOCIATED CONTENT

© 2018 American Chemical Society. This is an open access article distributed under the terms of the Creative Commons Attribution (CC-BY) License, which permits unrestricted use, distribution, and reproduction in any medium, provided the original work is properly cited.

© 2018 American Chemical Society. This is an open access article distributed under the terms of the Creative Commons Attribution (CC-BY) License, which permits unrestricted use, distribution, and reproduction in any medium, provided the original work is properly cited.

### AUTHOR INFORMATION

**Corresponding Author**

*E-mail: r.c.chiechi@rug.nl.*

**ORCID**

Hendrik W. de Vries: 0000-0002-9307-9015

Andreas Herrmann: 0000-0002-8886-0894

Ryan C. Chiechi: 0000-0002-0895-2095

**Present Addresses**

1. Institute of Technical and Macromolecular Chemistry, RWTH Aachen University, Worringerweg 2, 52074 Aachen, Germany (A.H.).

2. DWI-Leibniz Institute for Interactive Materials, Forckenbeckstr. 50, 52056 Aachen, Germany (A.H.).
The Zernike Institute of Advanced Materials is gratefully acknowledged for financial support.

ACKNOWLEDGMENTS

The authors declare no competing financial interest.

REFERENCES


